Amplifier Transistors

NPN Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
BC	0546 0547 0548	V _{CEO}	65 45 30	Vdc
BC	0546 0547 0548	V _{CBO}	80 50 30	Vdc
Emitter - Base Voltage		V_{EBO}	6.0	Vdc
Collector Current – Continuous		I _C	100	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C		P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = Derate above 25°C	= 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range		T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction–to–Case	$R_{ heta JC}$	83.3	°C/W

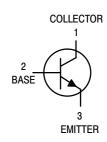
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.





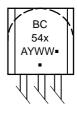
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



BC54x = Device Code

x = 6, 7, or 8

A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

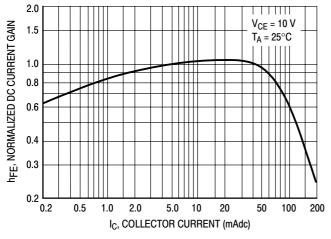
download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			1			
Collector – Emitter Breakdown Voltage	BC546	V _{(BR)CEO}	65	<u> </u>	Г _	V
$(I_C = 1.0 \text{ mA}, I_B = 0)$	BC547	V (BR)CEO	45	_	_	v
(IC = 1.0 IIIA, IB = 0)	BC548		30	_	_	
Callector Boso Brookdown Voltage		\/				V
Collector – Base Breakdown Voltage	BC546 BC547	V _{(BR)CBO}	80 50	_	_	V
$(I_C = 100 \mu\text{Adc})$	BC548		50 30	_	_	
5 '''		.,		_		
Emitter – Base Breakdown Voltage	BC546	$V_{(BR)EBO}$	6.0	_	_	V
$(I_E = 10 \mu A, I_C = 0)$	BC547		6.0	_	_	
	BC548		6.0	_	_	
Collector Cutoff Current		I _{CES}				
$(V_{CE} = 70 \text{ V}, V_{BE} = 0)$	BC546		_	0.2	15	nA
$(V_{CE} = 50 \text{ V}, V_{BE} = 0)$	BC547		_	0.2	15	
$(V_{CE} = 35 \text{ V}, V_{BE} = 0)$	BC548		_	0.2	15	
$(V_{CE} = 30 \text{ V}, T_A = 125^{\circ}\text{C})$	BC546/547/548		_	_	4.0	μΑ
ON CHARACTERISTICS		_			_	_
DC Current Gain		h _{FE}				-
$(I_C = 10 \mu A, V_{CE} = 5.0 V)$	BC547A	1	_	90	_	
	BC546B/547B/548B	1	_	150	-	
	BC548C	1	_	270	_	
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC546		110	_	450	
	BC547		110	_	800	
	BC548		110	_	800	
	BC547A		110	180	220	
	BC546B/547B/548B		200	290	450	
	BC547C/BC548C		420	520	800	
$(I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC547A/548A		_	120	_	
	BC546B/547B/548B		_	180	_	
	BC548C		_	300	-	
Collector – Emitter Saturation Voltage		V _{CE(sat)}				V
$(I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA})$		0=(00)	_	0.09	0.25	
$(I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA})$			_	0.2	0.6	
$(I_C = 10 \text{ mA}, I_B = \text{See Note 1})$			_	0.3	0.6	
Base - Emitter Saturation Voltage		V _{BE(sat)}	_	0.7	_	V
$(I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA})$		22(00.1)				
Base – Emitter On Voltage		V _{BE(on)}				V
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$		V BE(On)	0.55	_	0.7	•
$(I_C = 2.0 \text{ m/s}, V_{CE} = 3.0 \text{ V})$ $(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V})$			-	_	0.77	
		1	l	<u> </u>	•	<u>l</u>
SMALL-SIGNAL CHARACTERISTICS		_	1	1		1
Current – Gain – Bandwidth Product	D0546	f⊤				MHz
$(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz})$	BC546	1	150	300	_	
	BC547	1	150	300	_	
	BC548	1	150	300	_	
Output Capacitance		C _{obo}	_	1.7	4.5	pF
$(V_{CB} = 10 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz})$		<u> </u>	<u> </u>	<u> </u>	<u></u>	<u> </u>
Input Capacitance		C _{ibo}	_	10	_	pF
$(V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz})$]				
Small – Signal Current Gain		h _{fe}				_
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ kHz})$	BC546	· ·ie	125	_	500	
(.C =, *CE = 0.0 +, 1 = 1.0 ((12)	BC547/548	1	125	_	900	
	BC547A	1	125	220	260	
	BC546B/547B/548B	1	240	330	500	
	BC547C/548C		450	600	900	
Noise Figure	200 17 0/0400	NIE	700	000	555	40
Noise Figure	BC546	NF		2.0	10	dB
// 00-4 // 50// 5 0/0	BU54h	1	I -	2.0	10	1
$(I_C = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ V}, R_S = 2 \text{ k}\Omega,$				0 0	4.0	
$(I_C = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ V}, R_S = 2 \text{ k}\Omega,$ f = 1.0 kHz, Δ f = 200 Hz)	BC547 BC548		_	2.0 2.0	10 10	

^{1.} I_B is value for which I_C = 11 mA at V_{CE} = 1.0 V.

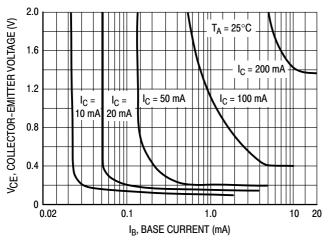
BC547/BC548



1.0 T_A = 25°C 0.9 0.8 $V_{BE(sat)} @ I_C/I_B = 10$ 0.7 V, VOLTAGE (VOLTS) V_{BE(on)} @ V_{CE} = 10 V 0.6 0.5 0.4 0.3 0.2 $V_{CE(sat)} @ I_C/I_B = 10$ 0.1 0.2 0.3 0.5 0.7 1.0 2.0 3.0 5.0 7.0 10 20 30 50 70 100 IC, COLLECTOR CURRENT (mAdc)

Figure 1. Normalized DC Current Gain

Figure 2. "Saturation" and "On" Voltages



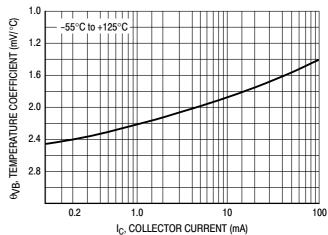
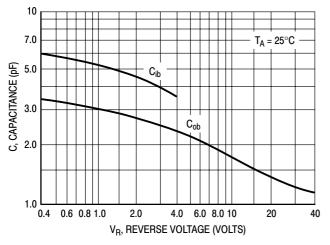


Figure 3. Collector Saturation Region

Figure 4. Base-Emitter Temperature Coefficient



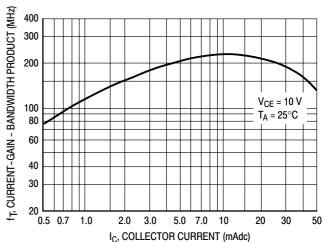


Figure 5. Capacitances

Figure 6. Current-Gain - Bandwidth Product

BC546

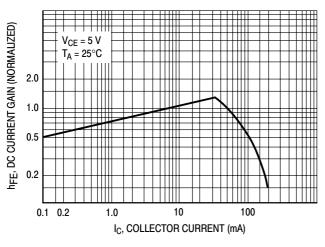


Figure 7. DC Current Gain

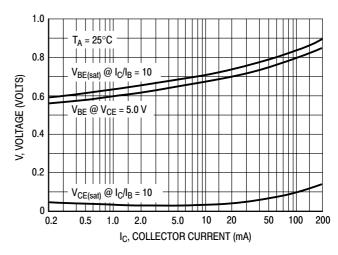


Figure 8. "On" Voltage

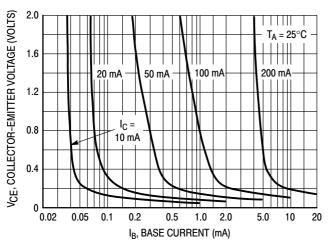


Figure 9. Collector Saturation Region

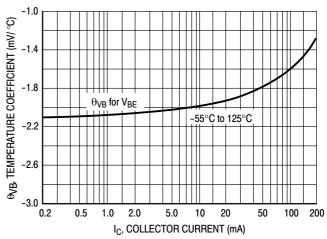


Figure 10. Base-Emitter Temperature Coefficient

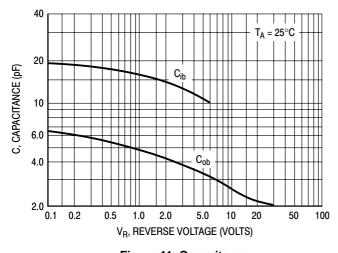


Figure 11. Capacitance

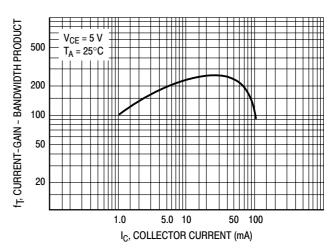


Figure 12. Current-Gain - Bandwidth Product

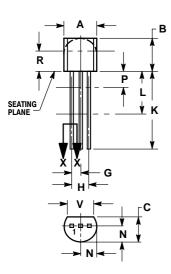
DEVICE ORDERING INFORMATION

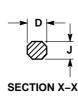
Device	Package	Shipping [†]
BC546B	TO-92	5000 Units / Bulk
BC546BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC546BRL1	TO-92	2000 / Tape & Reel
BC546BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC546BZL1	TO-92	2000 / Ammo Box
BC546BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547ARL	TO-92	2000 / Tape & Reel
BC547ARLG	TO-92 (Pb-Free)	2000 / Tape & Reel
BC547ARL1	TO-92	2000 / Tape & Reel
BC547ARL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC547AZL1	TO-92	2000 / Ammo Box
BC547AZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547B	TO-92	5000 Units / Bulk
BC547BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC547BRL1	TO-92	2000 / Tape & Reel
BC547BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC547BZL1	TO-92	2000 / Ammo Box
BC547BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547C	TO-92	5000 Units / Bulk
BC547CG	TO-92 (Pb-Free)	5000 Units / Bulk
BC547CZL1	TO-92	2000 / Ammo Box
BC547CZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC548B	TO-92	5000 Units / Bulk
BC548BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC548BRL1	TO-92	2000 / Tape & Reel
BC548BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC548BZL1	TO-92	2000 / Ammo Box
BC548BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC548C	TO-92	5000 Units / Bulk
BC548CG	TO-92 (Pb-Free)	5000 Units / Bulk
BC548CZL1	TO-92	2000 / Ammo Box
BC548CZL1G	TO-92 (Pb-Free)	2000 / Ammo Box

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AL





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 VIA EM 1000
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R
 IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
7	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
V	0.135		2 //2	

STYLE 17:

PIN 1. COLLECTOR 2. BASE 3. EMITTER

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